

30V N-Channel Enhancement Mode MOSFET

Description

The PECN4446SR uses trench MOSFET technology that is uniquely optimized to provide the most efficient high frequency switching performance. Conduction and switching losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and C_{rss} .

General Features

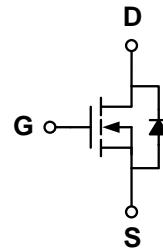
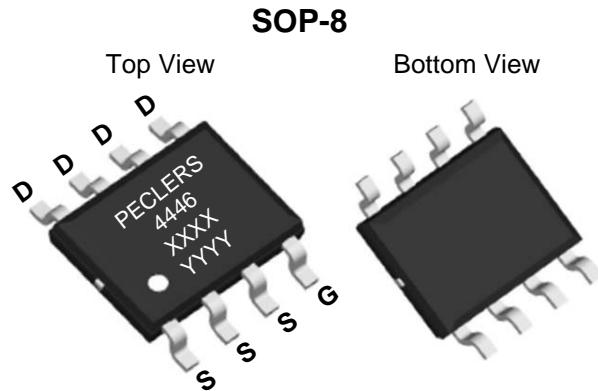
- ◆ $V_{DS} = 30V$ $I_D = 15A$
 $R_{DS(ON)}(\text{Typ.}) = 6.8m\Omega$ @ $V_{GS} = 10V$
 $R_{DS(ON)}(\text{Typ.}) = 9.0m\Omega$ @ $V_{GS} = 4.5V$
- ◆ Lead free product is acquired
- ◆ Surface mount package

Application

- ◆ High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- ◆ Networking DC-DC Power System
- ◆ Load switch

Package

- ◆ SOP-8 100% UIS TESTED!
- 100% ΔV_{ds} TESTED!

Schematic diagram**Marking and pin assignment**

XXXX—Date Code
YYYY—Quality Code.

**Ordering Information**

Part Number	Storage Temperature	Package	Devices Per Reel
PECN4446SR	-55°C to +150°C	SOP-8	4000

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

parameter	symbol	limit	unit
Drain-source voltage	V_{DS}	30	V
Gate-source voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	15	A
		12	
Pulsed Drain Current	I_{DP}	40	A
Avalanche energy(L=0.1mH)	E_{AS}	50	mJ
Power Dissipation	P_D	3	W
		2.1	
Operating junction Temperature range	T_j	-55—150	°C

Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	30	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =30V, V _{GS} =0V T _J =85°C	-	-	1	μA
			-	-	5	
Gate Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.8	1.6	2.2	V
Drain-source on-state resistance ¹	R _{DS(ON)}	V _{GS} =10V, I _D =15A	-	6.8	8.5	mΩ
		V _{GS} =4.5V, I _D =11A		9	12	
On Status Drain Current	I _{D(ON)}	V _{DS} =10V, V _{GS} =5V	40	-	-	A
Diode Characteristics						
Diode Forward Voltage	V _{SD}	I _{SD} =1A, V _{GS} =0V	-	0.82	1.1	V
Diode Continuous Forward Current	I _S		-	-	4	A
Reverse Recovery Time	t _{rr}	I _F =15A, dI/dt=100A/μs	-	28	-	ns
Reverse Recovery Charge	Q _{rr}		-	40	-	nC
Dynamic Characteristics						
Gate Resistance	R _G	V _{GS} =0V, V _{DS} =0V,f=1MHz	-	0.47	0.7	Ω
Input capacitance	C _{ISS}	V _{GS} =0V ,V _{DS} =15V f=1.0MHz	-	985	-	pF
Output capacitance	C _{OSS}		-	205	-	
Reverse transfer capacitance	C _{RSS}		-	76	-	
Turn-on delay time	t _{D(ON)}	V _{GS} =10V, V _{DS} =15V, R _L =1Ω, R _G =3Ω	-	7	-	ns
Turn-on Rise time	tr		-	8	-	
Turn-off delay time	t _{D(OFF)}		-	22	-	
Turn-off Fall time	t _f		-	6.8	-	
Total gate charge	Q _g	V _{GS} =10V, V _{DS} =15V,I _D =15A	-	18	27	nC
Gate-source charge	Q _{gs}			2.4		
Gate-drain charge	Q _{gd}		-	2.3	-	

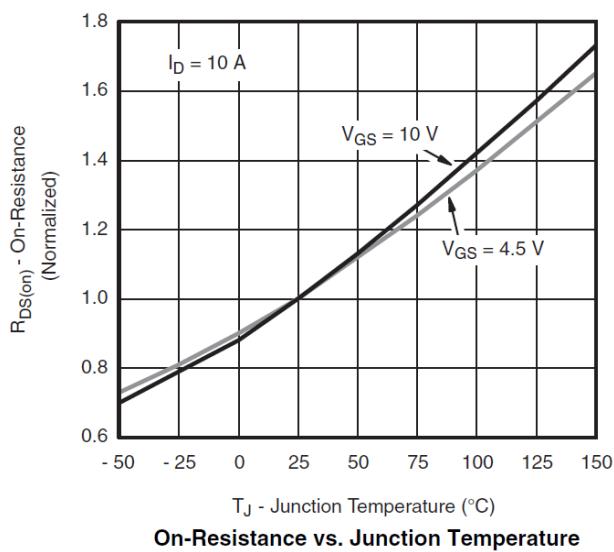
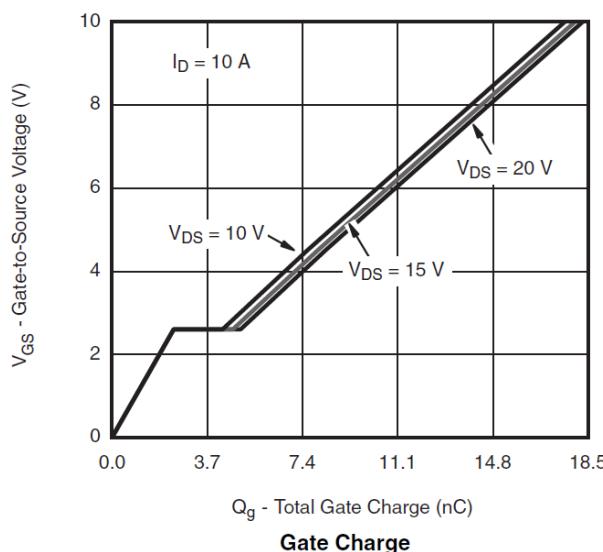
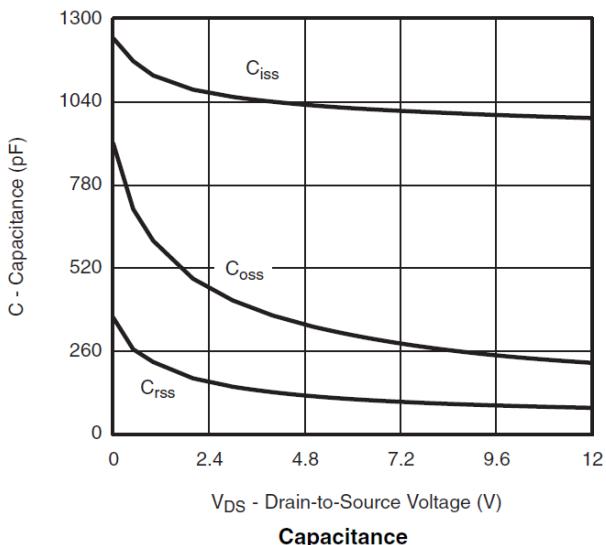
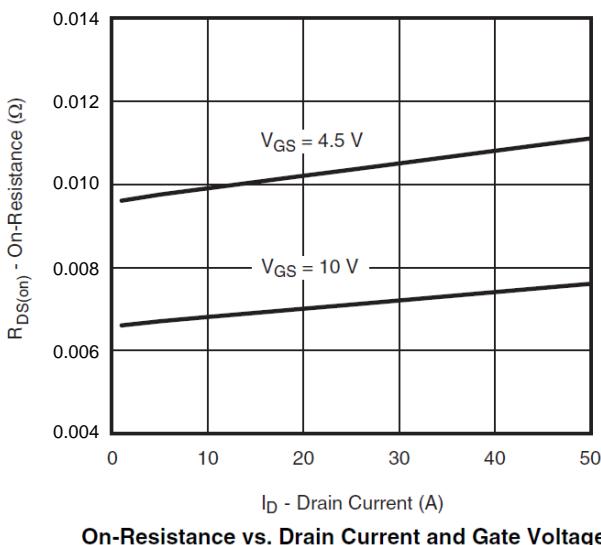
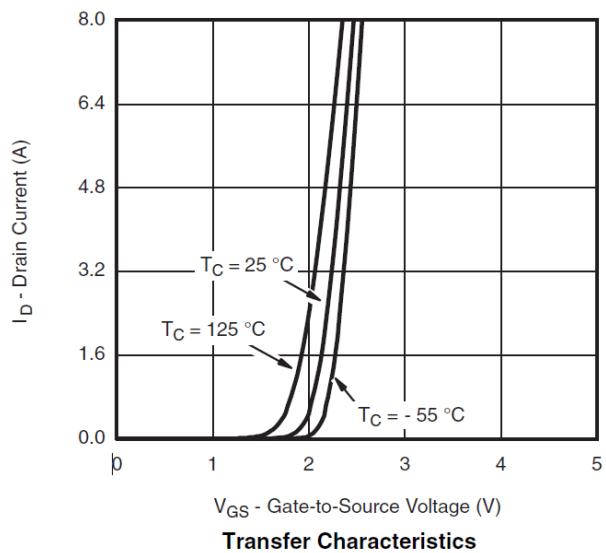
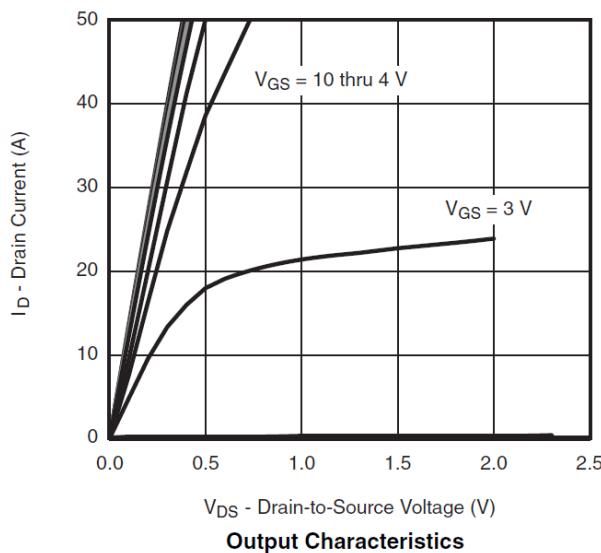
Thermal Characteristics

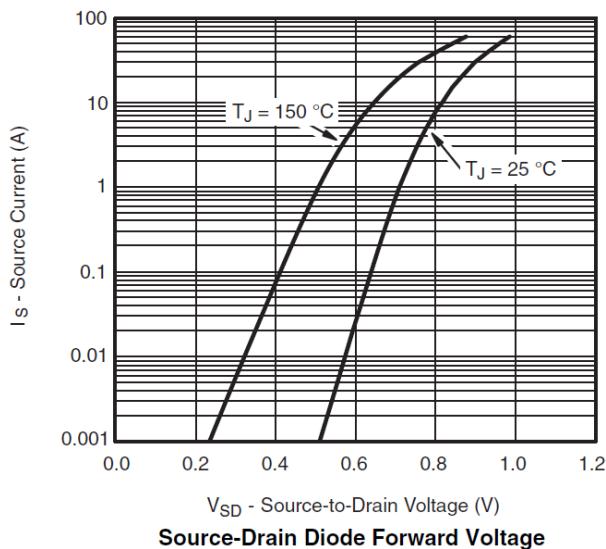
Parameter	Symbol	Typ	Max	Unit
Maximum Junction-to-Ambient ^A	≤ 10s	R _{θJA}	33	°C/W
Maximum Junction-to-Ambient ^A	Steady-State		59	
Maximum Junction-to-Lead ^B	Steady-State		16	

A: The value of R qJA is measured with the device mounted on 1in 2 FR-4 board with 2oz. Copper, in a still air environment with T A=25°C. The value in any given application depends on the user's specific board design. The current rating is based on the t ≤ 10s thermal resistance rating.

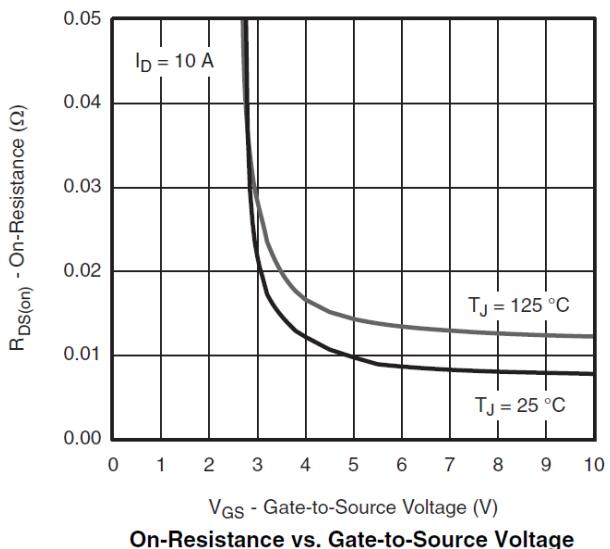
B: The R qJA is the sum of the thermal impedance from junction to lead R qJL and lead to ambient.

Typical Performance Characteristics

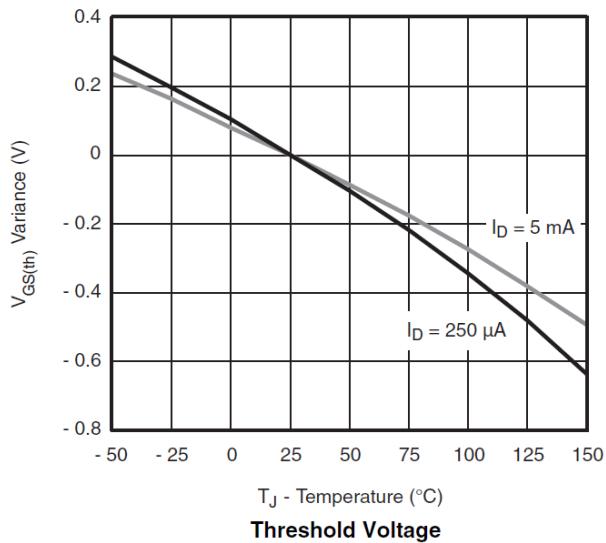




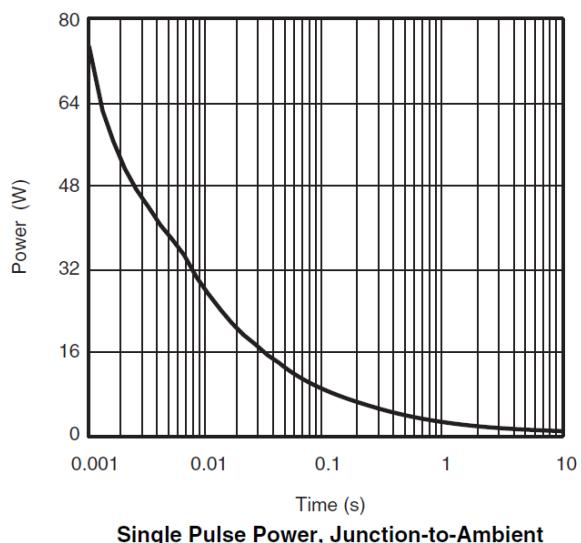
Source-Drain Diode Forward Voltage



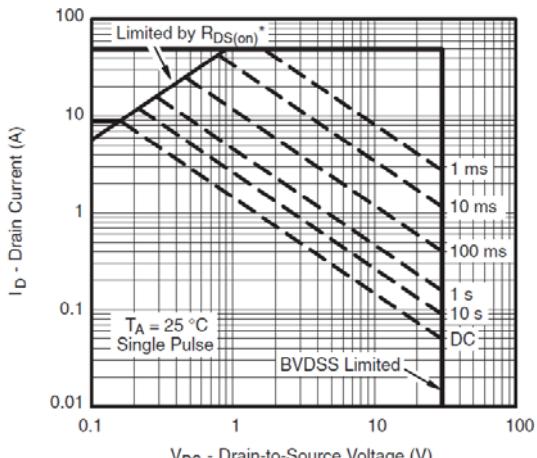
On-Resistance vs. Gate-to-Source Voltage



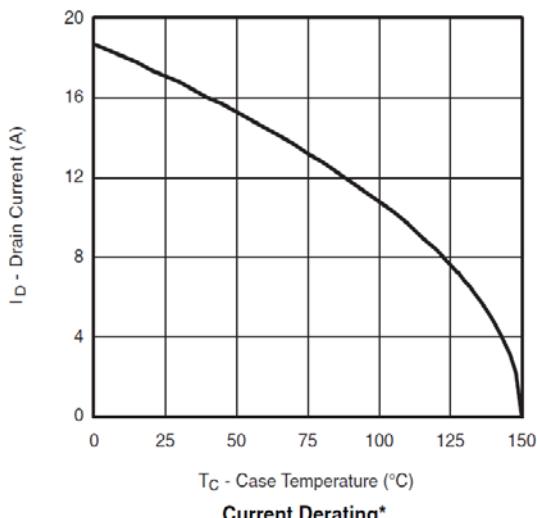
Threshold Voltage



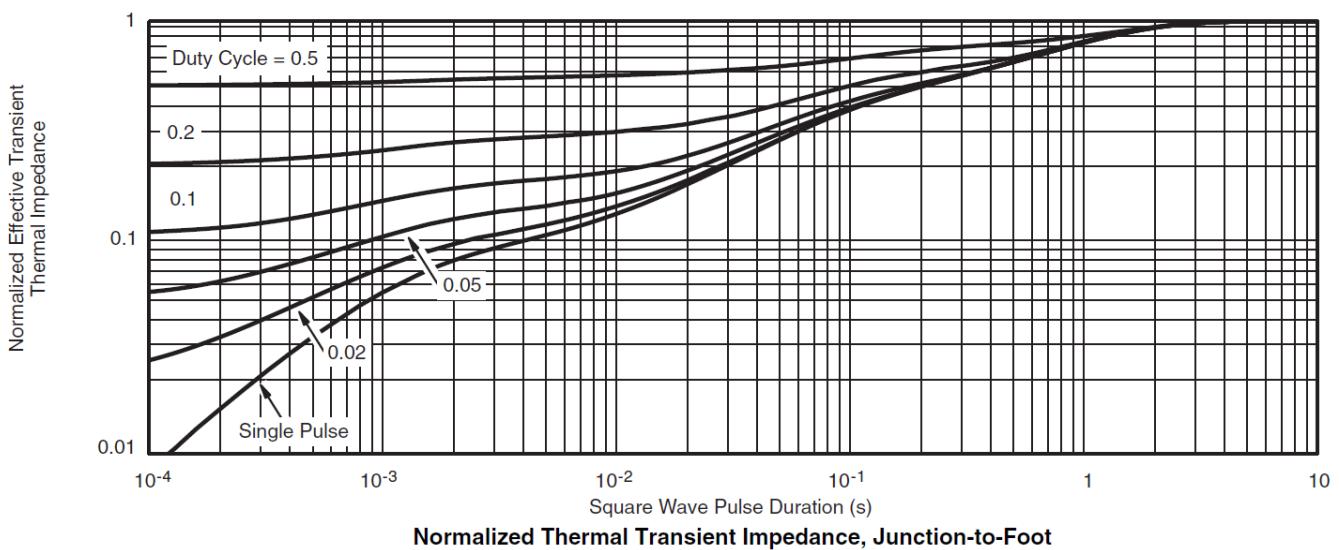
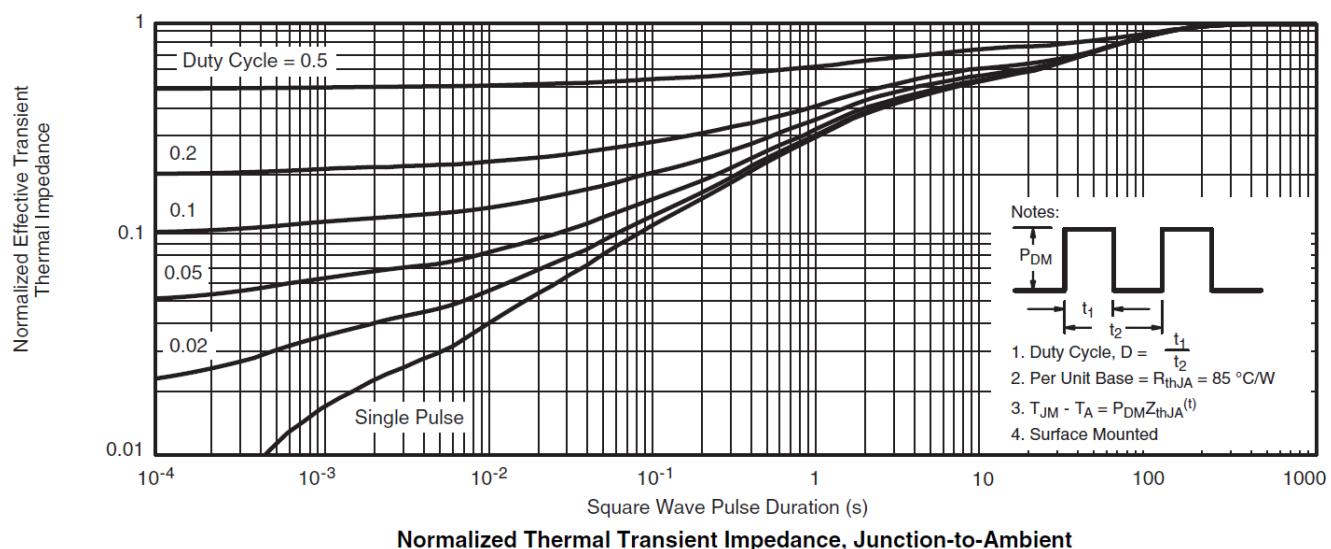
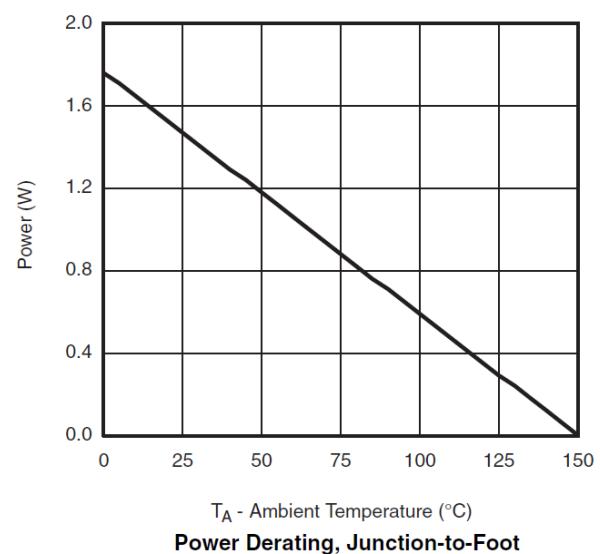
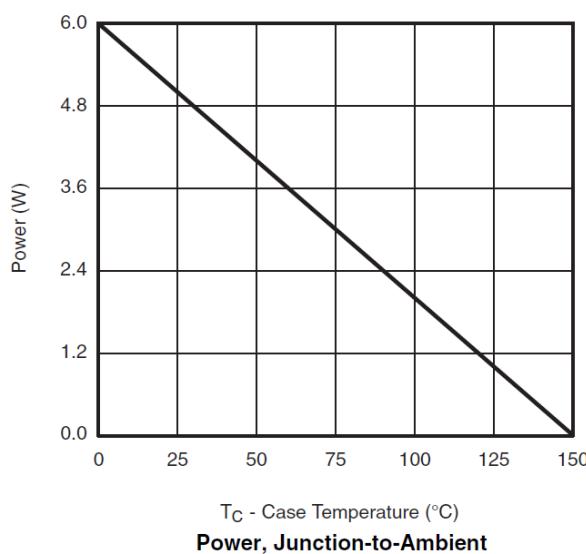
Single Pulse Power, Junction-to-Ambient



* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified
Safe Operating Area, Junction-to-Ambient

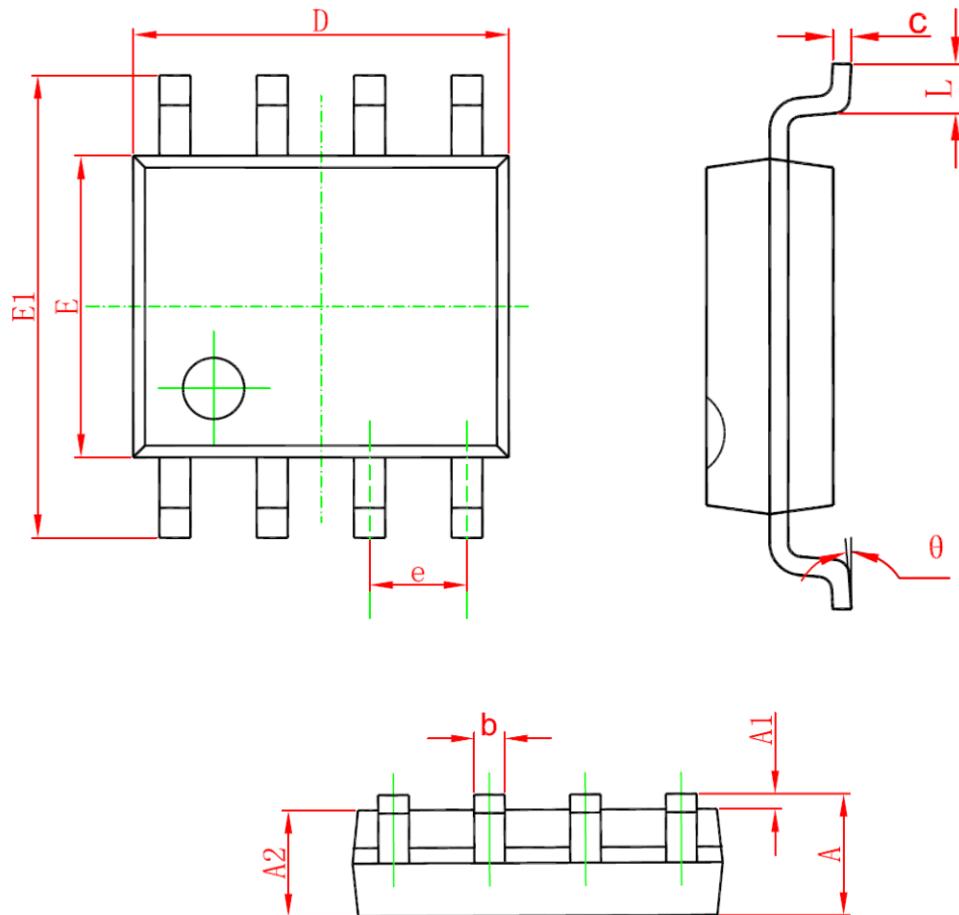


Current Derating*



Package Information

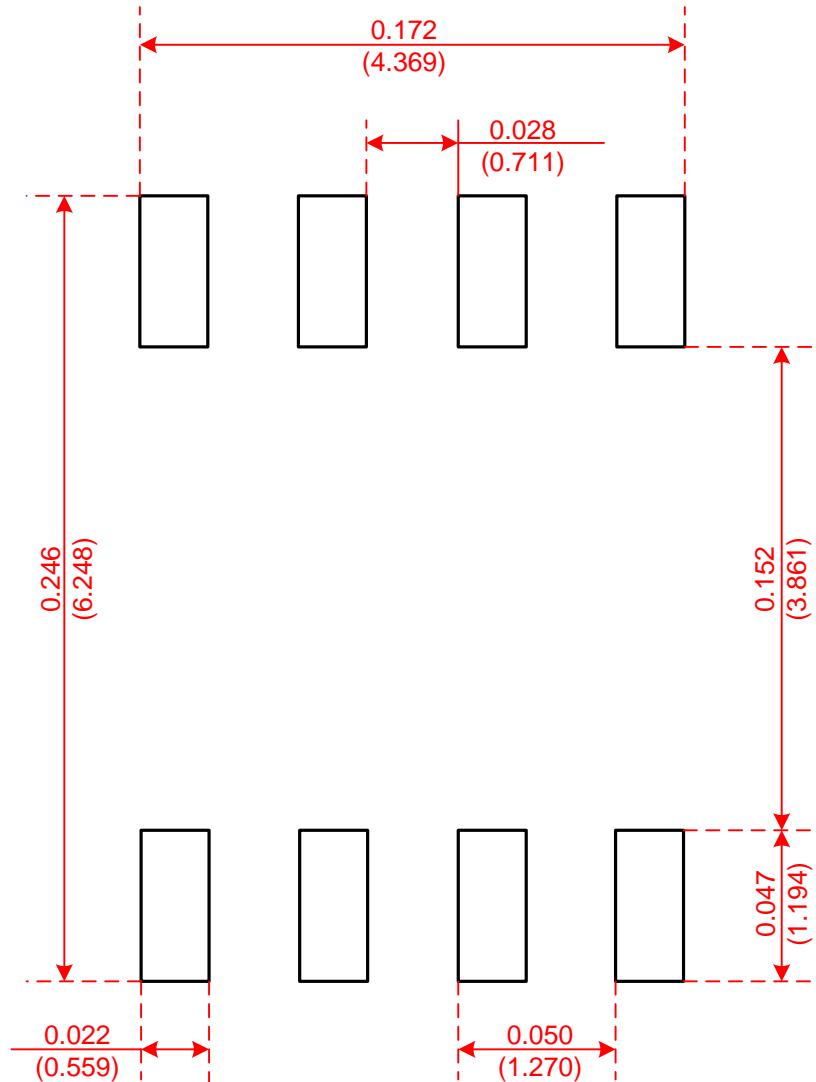
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Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Recommended Minimum Pads

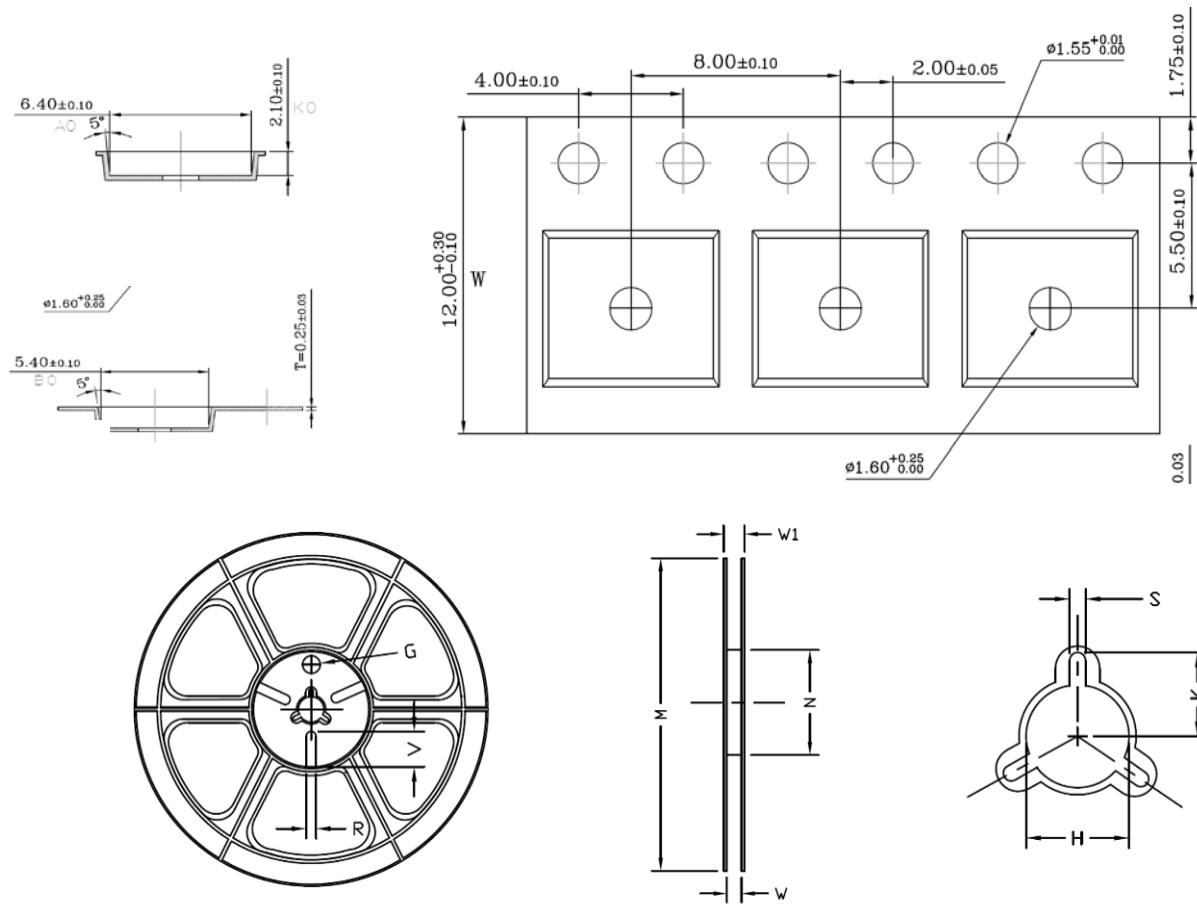
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Recommended Minimum Pads
Dimensions in Inches/(mm)

Tape and Reel

- SOP-8



Tape Size	Reel Size	M	N	W	W1	H	K	S	G	R	V
12mm	Ø330	Ø330.00 ±0.50	Ø97.00 ±0.30	13.00 ±0.30	17.40 ±1.00	Ø13.00 ±0.5	10.6	2.00 ±0.50	—	—	—

Unit Per Reel:
4000pcs

